

Features

- High Density Cell Design For Ultra Low R_{DS(on)}
- · High Speed Switching
- ESD Protected Up to 2.5KV (HBM)
- Trench Power LV MOSFET Technology
- Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- · Halogen Free Available Upon Request By Adding Suffix "-HF"
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

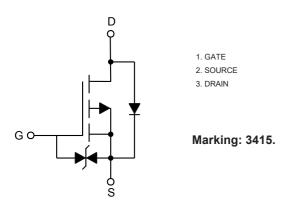
Maximum Ratings

- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 96°C/W Junction to Ambient^(Note1)

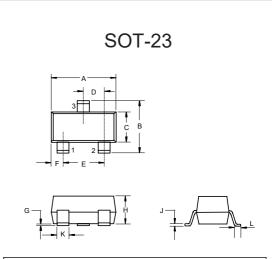
F	Symbol	Rating	Unit		
Drain-Source Voltage		V _{DS}	-20	V	
Gate-Source Volltage		V _{GS}	±12	V	
Drain Current	T _A =25°C Steady State	ı	-5.6	Α	
	T _A =70°C Steady State	I _D	-4.5	A	
Pulsed Drain Current ^(Note2)		I _{DM}	-23	Α	
Total Power Dissipation		P _D	1.3	W	

Note 1.Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch.
2.Pulse Test: Pulse Width≤300us,Duty cycle ≤2%.

Internal Structure:

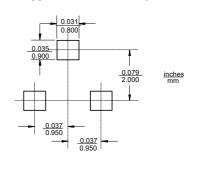


P-Channel Enhancement Mode Field Effect Transistor



DIMENSIONS					
DIM	INCHES		MM		NOTE
DIIVI	MIN	MAX	MIN	MAX	NOTE
Α	0.110	0.120	2.80	3.04	
В	0.083	0.104	2.10	2.64	
С	0.047	0.055	1.20	1.40	
D	0.034	0.041	0.85	1.05	
Е	0.067	0.083	1.70	2.10	
F	0.018	0.024	0.45	0.60	
G	0.0004	0.006	0.01	0.15	
Н	0.035	0.043	0.90	1.10	
J	0.003	0.007	0.08	0.18	
K	0.012	0.020	0.30	0.51	
L	0.007	0.020	0.20	0.50	

Suggested Solder Pad Layout



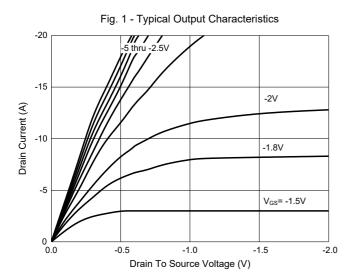


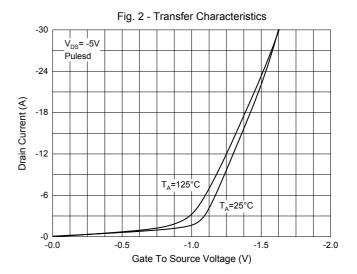
Electrical Characteristics @ 25°C (Unless Otherwise Specified)

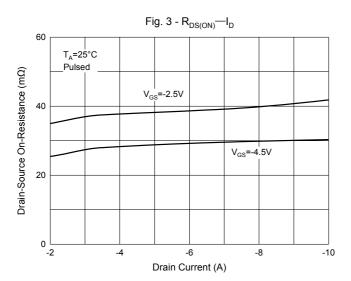
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics					l		
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	-20			V	
		$V_{DS} = 0V, V_{GS} = \pm 10V$		±2.5	±10	μA	
Gate-Source Leakage Current	I _{GSS}	V_{DS} =0V, V_{GS} = $\pm 8V$		±0.9	±2	μA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-20V, V _{GS} =0V			-1	μA	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_D=-250\mu A$	-0.40	-0.62	-1.0	V	
		V _{GS} =-4.5V, I _D =-5.6A		29	42		
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =-2.5V, I _D =-4.3A		36	55	mΩ	
		V _{GS} =-1.8V, I _D =-2A		55	100	1	
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =-5.6A		-0.8	-1.2	V	
Maximum Body-Diode Continuous Current	I _S				-5.6	Α	
Dynamic Characteristics							
Input Capacitance	C _{iss}			940		pF	
Output Capacitance	C _{oss}	V_{DS} =-10V, V_{GS} =0V,f=1MHz		219			
Reverse Transfer Capacitance	C _{rss}			116			
Switching Characteristics							
Total Gate Charge	Q_g			7.2		nC	
Gate-Source Charge	Q_{gs}	V _{DS} =-10V,V _{GS} =-4.5V,I _D =-4A		1.2			
Gate-Drain Charge	Q_{gd}			1.6			
Turn-On Delay Time	t _{d(on)}			15			
Turn-On Rise Time	t _r	V_{GS} =-4.5V, V_{DS} =-10V, R_L =2.5 Ω ,		63		- ns	
Turn-Off Delay Time	t _{d(off)}	R_{GEN} =3 Ω		21			
Turn-Off Fall Time	t _f			12			

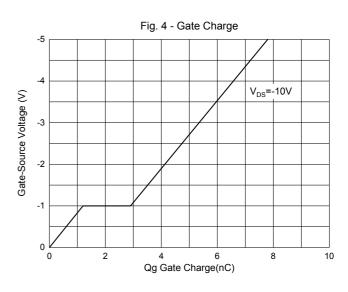


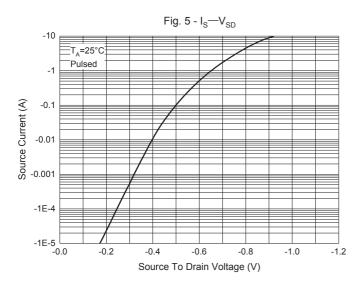
Curve Characteristics

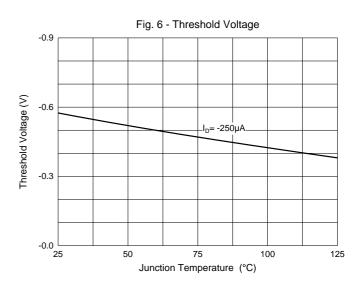














Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel

Note: Adding "-HF" Suffix For Halogen Free, eg. Part Number-TP-HF

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